SLVS178B - DECEMBER 1998 - REVISED MAY 2001

- 100-mA Low-Dropout Regulator
- Fixed Output Voltage Options: 5 V, 3.8 V, 3.3 V, 3.2 V, and 3 V
- Dropout Typically 170 mV at 100-mA
- Thermal Protection
- Less Than 1 μA Quiescent Current in Shutdown
- -40°C to 125°C Operating Junction Temperature Range
- 5-Pin SOT-23 (DBV) Package
- ESD Protection Verified to 1.5 KV Human Body Model (HBM) per MIL-STD-883C

# DBV PACKAGE (TOP VIEW) EN GND IN 3 2 1 4 5 NC OUT

NC - No internal connection

#### description

The TPS761xx is a 100 mA, low dropout (LDO) voltage regulator designed specifically for battery-powered applications. A proprietary BiCMOS fabrication process allows the TPS761xx to provide outstanding performance in all specifications critical to battery-powered operation.

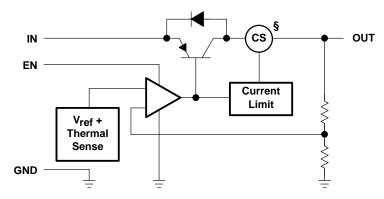
The TPS761xx is available in a space-saving SOT-23 (DBV) package and operates over a junction temperature range of –40°C to 125°C.

#### **AVAILABLE OPTIONS**

TJ	VOLTAGE	PACKAGE	PART N	UMBER	SYMBOL
	3 V		TPS76130DBVR <sup>†</sup>	TPS76130DBVT‡	PAEI
	3.2 V		TPS76132DBVR <sup>†</sup>	TPS76132DBVT‡	PAFI
-40°C to 125°C	3.3 V	SOT-23 (DBV)	TPS76133DBVR <sup>†</sup>	TPS76133DBVT‡	PAII
	3.8 V	(554)	TPS76138DBVR <sup>†</sup>	TPS76138DBVT‡	PAKI
	5 V		TPS76150DBVR†	TPS76150DBVT‡	PALI

<sup>†</sup>The DBVR passive indicates tape and reel of 3000 parts.

#### functional block diagram



§ Current sense



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



<sup>&</sup>lt;sup>‡</sup>The DBVT passive indicates tape and reel of 250 parts.

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#### **Terminal Functions**

TERM	TERMINAL I/O		DESCRIPTION							
NAME	NO.	1/0	DESCRIFTION							
EN	3	I	Enable input							
GND	2		Ground							
IN	1	I	Input voltage							
NC	4		No connection							
OUT	5	0	Regulated output voltage							

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Input voltage range, V <sub>I</sub> (see Note 1)	–0.3 V to 16 V
Voltage range at EN	0.3 V to V <sub>I</sub> + 0.3 V
Peak output current	internally limited
Continuous total dissipation	See Dissipation Rating Table
Operating junction temperature range, T <sub>J</sub>	–40°C to 150°C
Storage temperature range, T <sub>stq</sub>	65°C to 150°C
ESD rating, HBM	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltages are with respect to device GND pin.

#### **DISSIPATION RATING TABLE**

BOARD	PACKAGE	$R_{ heta}$ JC	$R_{ heta JA}$	$R_{\theta}$ JA DERATING FACTOR ABOVE $T_A = 25^{\circ}C$		T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING	
Low K‡	DBV	65.8 °C/W	259 °C/W	3.9 mW/°C	386 mW	212 mW	154 mW	
High K§	DBV	65.8 °C/W	180 °C/W	5.6 mW/°C	555 mW	305 mW	222 mW	

<sup>‡</sup> The JEDEC Low K (1s) board design used to derive this data was a 3 inch x 3 inch, two layer board with 2 ounce copper traces on top of the board. § The JEDEC High K (2s2p) board design used to derive this data was a 3 inch x 3 inch, multilayer board with 1 ounce internal power and ground planes and 2 ounce copper traces on top and bottom of the board.

#### recommended operating conditions

		MIN	NOM MAX	UNIT
	TPS76130	3.35	16	
	TPS76132	3.58	16	1
Input voltage, V <sub>I</sub>	TPS76133	3.68	16	V
	TPS76138	4.18	16	1
	TPS76150	5.38	16	
Continuous output current, I	)	0	100	mA
Operating junction temperate	ıre, TJ	-40	125	°C

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## electrical characteristics over recommended operating free-air temperature range, V<sub>I</sub> = V<sub>O(typ)</sub> + 1 V, I<sub>O</sub> = 1 mA, EN = V<sub>I</sub>, C<sub>o</sub> = 4.7 $\mu$ F (unless otherwise noted)

PARAMETER			TEST CO	TEST CONDITIONS			MAX	UNIT		
			T <sub>J</sub> = 25°C		2.96	3	3.04			
		TPS76130	T <sub>J</sub> = 25°C,	1 mA < I <sub>O</sub> < 100 mA	2.9		3.04	V		
			1 mA < I <sub>O</sub> < 100 mA		2.89		3.07			
			T <sub>J</sub> = 25°C	3.16	3.2	3.24				
		TPS76132	T <sub>J</sub> = 25°C,	3.11		3.24	V			
			1 mA < I <sub>O</sub> < 100 mA		3.08		3.3			
			T <sub>J</sub> = 25°C	3.26	3.3	3.34				
٧o	Output voltage	TPS76133	T <sub>J</sub> = 25°C,	1 mA < I <sub>O</sub> < 100 mA	3.21		3.34	V		
			1 mA < I <sub>O</sub> < 100 mA		3.18		3.4			
			T <sub>J</sub> = 25°C		3.76	3.8	3.84			
		TPS76138	T <sub>J</sub> = 25°C,	1 mA < I <sub>O</sub> < 100 mA	3.71		3.84	V		
			1 mA < I <sub>O</sub> < 100 mA		3.68		3.9	1		
		TPS76150	T <sub>J</sub> = 25°C		4.95	5	5.05	5		
			T <sub>J</sub> = 25°C,	1 mA < I <sub>O</sub> < 100 mA	4.88		5.05			
			1 mA < I <sub>O</sub> < 100 mA		4.86		5.1	1		
I <sub>I(standby)</sub>	Standby current		EN = 0 V				1	μΑ		
			$I_O = 0 \text{ mA},$	T <sub>J</sub> = 25°C		90	115			
			$I_O = 0 \text{ mA}$				130			
			$I_O = 1 \text{ mA},$	T <sub>J</sub> = 25°C		100	130			
			I <sub>O</sub> = 1 mA				170			
	0:	NID ()	I <sub>O</sub> = 10 mA,	T <sub>J</sub> = 25°C		190	220			
	Quiescent current (G	SND current)	I <sub>O</sub> = 10 mA				260	μΑ		
			I <sub>O</sub> = 50 mA,	T <sub>J</sub> = 25°C		850	1100			
			I <sub>O</sub> = 50 mA				1200	1		
			I <sub>O</sub> = 100 mA,	T <sub>J</sub> = 25°C		2600	3600	1		
			I <sub>O</sub> = 100 mA				4000			
		TPS76130	4 V < V <sub>I</sub> < 16,	I <sub>O</sub> = 1 mA		3	10			
		TPS76132	4.2 V < V <sub>I</sub> < 16,	V < V <sub>I</sub> < 16, I <sub>O</sub> = 1 mA		3	10			
	Input regulation	TPS76133	4.3 V < V <sub>I</sub> < 16,	I <sub>O</sub> = 1 mA		3	10	mV		
		TPS76138	4.8 V < V <sub>I</sub> < 16,	I <sub>O</sub> = 1 mA		3	10	1 !		
		TPS76150	6 V < V <sub>I</sub> < 16	I <sub>O</sub> = 1 mA		3	10			
Vn	Output noise voltage		BW = 300 Hz to 50 kHz	$C_0 = 10 \mu\text{F},  \text{T}_J = 25^{\circ}\text{C}$		190		μVrms		
	Ripple rejection		$f = 1 \text{ kHz},  C_0 = 10 \mu\text{F},$			63		dB		

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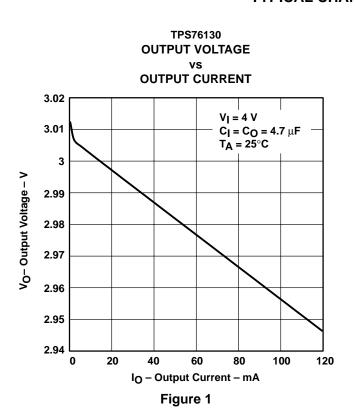
## electrical characteristics over recommended operating free-air temperature range, $V_I = V_{O(typ)} + 1 \text{ V}$ , $I_O = 1 \text{ mA}$ , $EN = V_I$ , $C_O = 4.7 \, \mu\text{F}$ (unless otherwise noted) (continued)

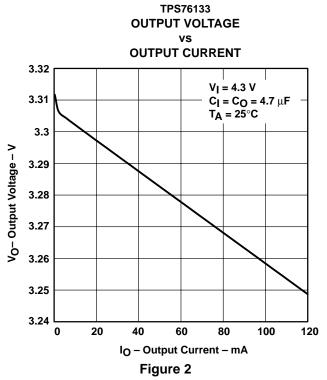
PARAMETER	TEST CONDITIONS	MIN TYP I	MAX UNIT
	$I_O = 0 \text{ mA},$ $T_J = 25^{\circ}\text{C}$	1	3
	$I_O = 0 \text{ mA}$		5
	$I_O = 1 \text{ mA},$ $T_J = 25^{\circ}\text{C}$	7	10
	I <sub>O</sub> = 1 mA		15
Dropout voltage	$I_{O} = 10 \text{ mA},   T_{J} = 25^{\circ}\text{C}$	40	60 mV
Dropout voltage	I <sub>O</sub> = 10 mA		90
	$I_O = 50 \text{ mA},$ $T_J = 25^{\circ}\text{C}$	120	150
	I <sub>O</sub> = 50 mA		180
	$I_{O} = 100 \text{ mA},   T_{J} = 25^{\circ}\text{C}$	170	240
	I <sub>O</sub> = 100 mA		280
Peak output current/current limit		100 125	135 mA
High level enable input		2	V
Low level enable input			0.8 V
I. Input surrent (FNI)	EN = 0 V	-1 0	1
II Input current (EN)	EN = V <sub>I</sub>	2.5	μA

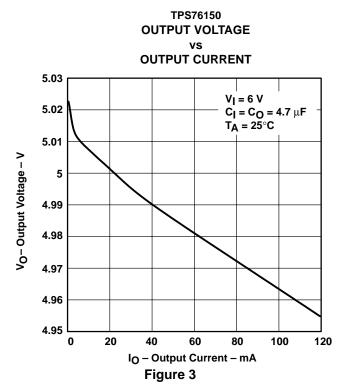
#### **TYPICAL CHARACTERISTICS**

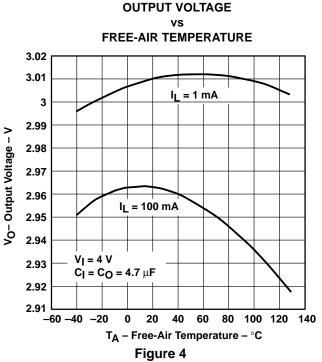
#### **Table of Graphs**

			FIGURE
\/ <sub>-</sub>	Output voltage	vs Output current	1, 2, 3
Vo	Output voltage	vs Free-air temperature	4, 5, 6
	Ground current	vs Free-air temperature	7, 8, 9
	Output noise	vs Frequency	10
Zo	Output impedance	vs Frequency	11
VDO	Dropout voltage	vs Free-air temperature	12
	Line transient response		13, 15
	Load transient response		14, 16

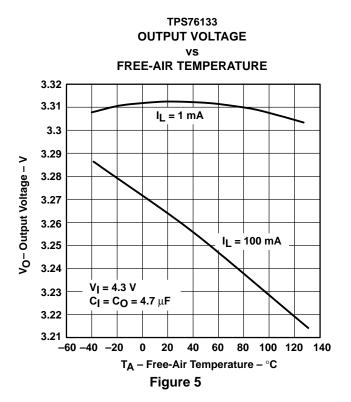


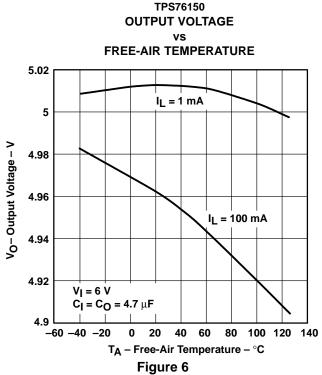






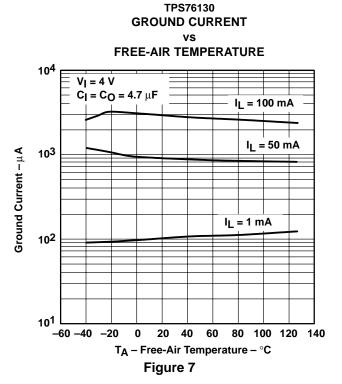
**TPS76130** 

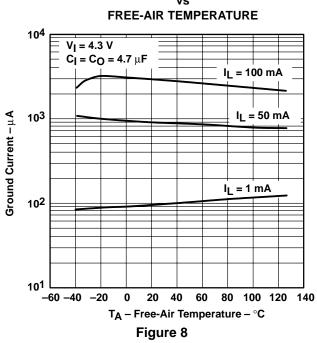


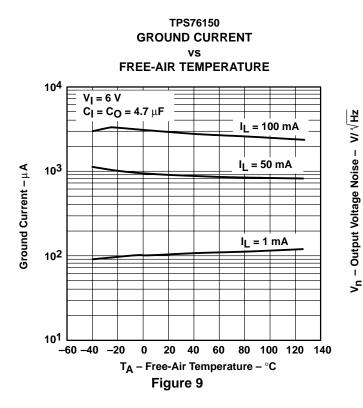


**TPS76133** 

**GROUND CURRENT** 







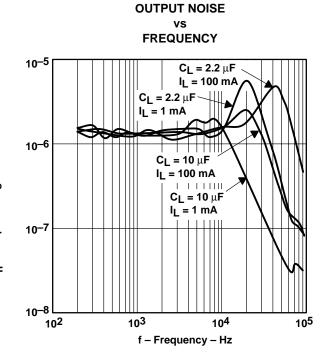
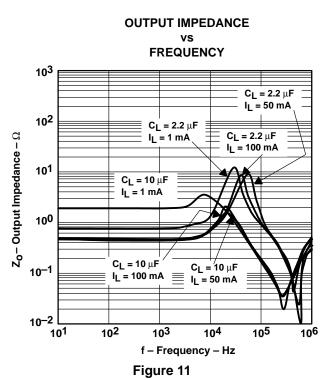
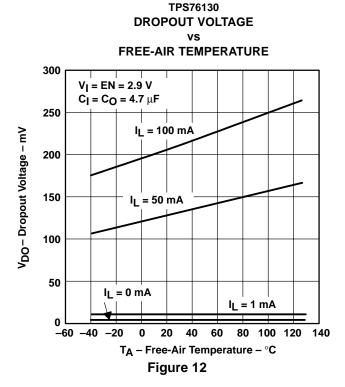


Figure 10





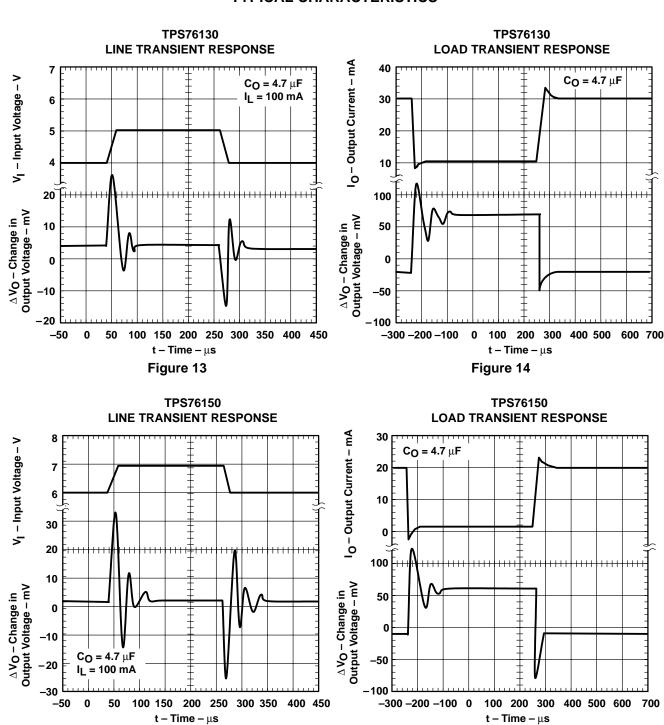




Figure 16

Figure 15

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#### **APPLICATION INFORMATION**

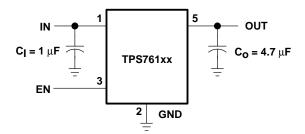


Figure 17. TPS761xx Typical Application

#### over current protection

The over current protection circuit forces the TPS761xx into a constant current output mode when the load is excessive or the output is shorted to ground. Normal operation resumes when the fault condition is removed.

#### NOTE:

An overload or short circuit may also activate the over temperature protection if the fault condition persists.

#### over temperature protection

The thermal protection system shuts the TPS761xx down when the junction temperature exceeds 160°C. The device recovers and operates normally when the temperature drops below 150°C.

#### input capacitor

A 1- $\mu$ F or larger ceramic decoupling capacitor with short leads connected between IN and GND is recommended. The decoupling capacitor may be omitted if there is a 1  $\mu$ F or larger electrolytic capacitor connected between IN and GND and located reasonably close to the TPS761xx. However, the small ceramic device is desirable even when the larger capacitor is present, if there is a lot of high frequency noise present in the system.

#### output capacitor

Like all low dropout regulators, the TPS761xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance value is 4.7  $\mu$ F and the ESR (equivalent series resistance) must be between 0.1  $\Omega$  and 10  $\Omega$ . Solid tantalum electrolytic, aluminum electrolytic, and multilayer ceramic capacitors are all suitable, provided they meet the requirements described above. Most of the commercially available 4.7- $\mu$ F surface-mount solid-tantalum capacitors, including devices from Sprague, Kemet, and Nichicon, meet the ESR requirements stated above. Multilayer ceramic capacitors should have minimum values of 4.7  $\mu$ F over the full operating temperature range of the equipment.

#### enable (EN)

A logic zero on the enable input shuts the TPS761xx off and reduces the supply current to less than 1  $\mu$ A. Pulling the enable input high causes normal operation to resume. If the enable feature is not used, EN should be connected to IN to keep the regulator on all of the time. The EN input must not be left floating.

#### reverse current path

The power transistor used in the TPS761xx has an inherent diode connected between IN and OUT as shown in the functional block diagram. This diode conducts current from the OUT terminal to the IN terminal whenever IN is lower than OUT by a diode drop. This condition does not damage the TPS761xx provided the current is limited to 150 mA.



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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS Lead finish/ (3) Ball material		MSL rating/ Peak reflow	Op temp (°C)	Part marking
•	(-)	(-)			(0)	(4)	(5)		(-)
TPS76130DBVR	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PAEI
TPS76130DBVT	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PAEI
TPS76132DBVR	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PAFI
TPS76132DBVT	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PAFI
TPS76133DBVR	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PAII
TPS76133DBVT	Obsolete	Production	SOT-23 (DBV)   5	-	-	Call TI	Call TI	-40 to 125	PAII
TPS76138DBVR	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU   SN   NIPDAU	Level-1-260C-UNLIM	-40 to 125	PAKI
TPS76138DBVT	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU   SN   NIPDAU	Level-1-260C-UNLIM	-40 to 125	PAKI
TPS76150DBVR	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU   NIPDAU	Level-1-260C-UNLIM	-40 to 125	PALI
TPS76150DBVT	Obsolete	Production	SOT-23 (DBV)   5	-	-	Call TI	Call TI	-40 to 125	PALI

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



#### PACKAGE OPTION ADDENDUM

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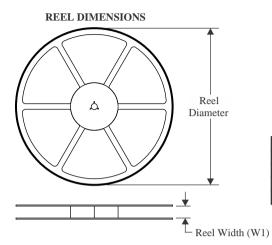
continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



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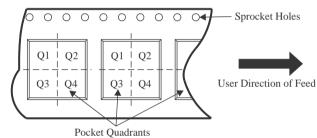
#### TAPE AND REEL INFORMATION



## TAPE DIMENSIONS KO P1 BO W Cavity A0

Γ	A0	Dimension designed to accommodate the component width
	В0	Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
	P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

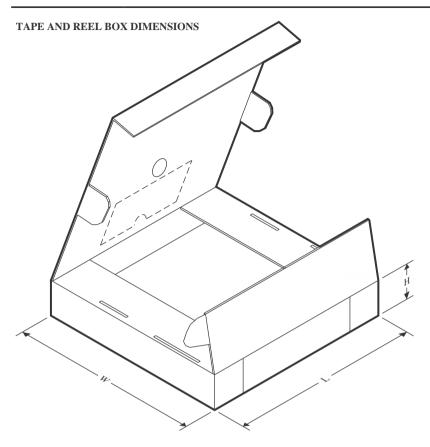


#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS76130DBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS76130DBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS76132DBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS76132DBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS76133DBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS76138DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS76138DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS76150DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS76150DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3



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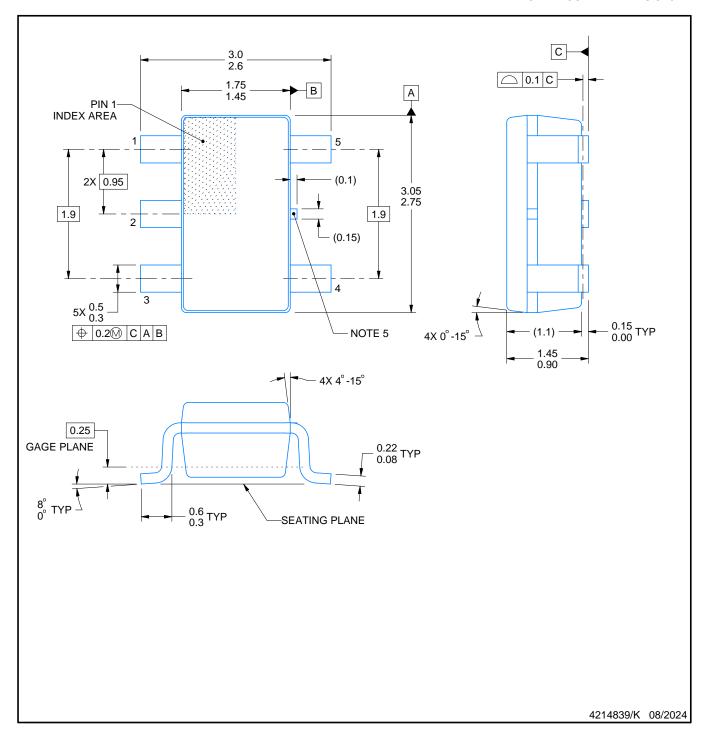


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS76130DBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TPS76130DBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TPS76132DBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TPS76132DBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TPS76133DBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TPS76138DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS76138DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TPS76150DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS76150DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0



SMALL OUTLINE TRANSISTOR



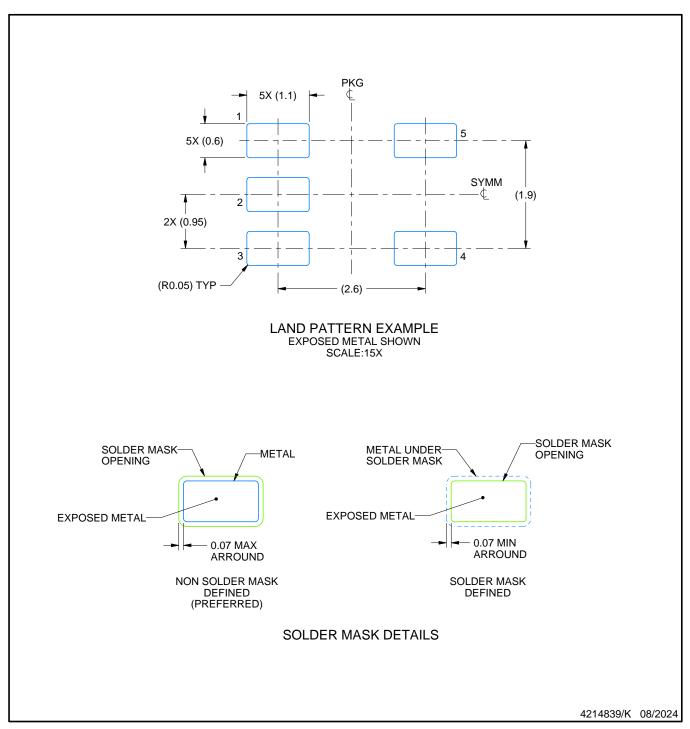
#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
  3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



SMALL OUTLINE TRANSISTOR



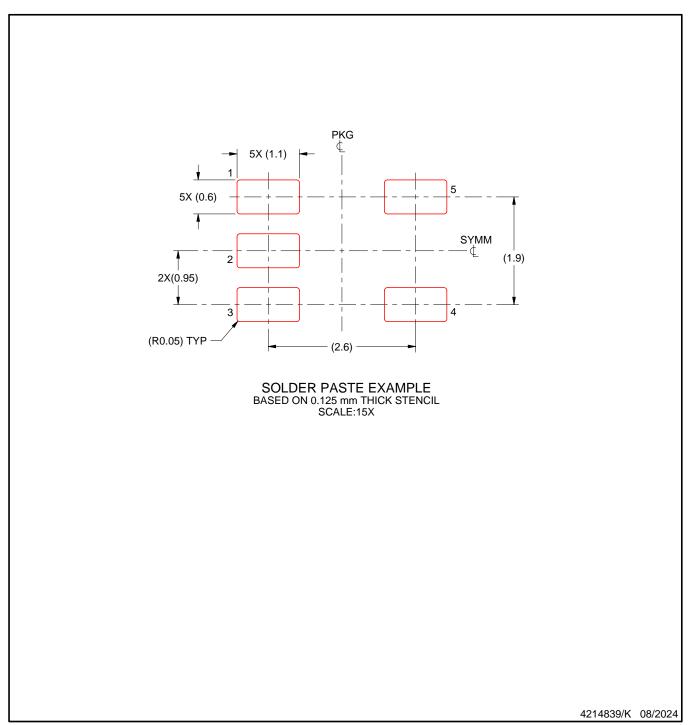
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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